Siemens Matsushita Components

SAW Components
Low Loss Filter

B4836
270,00 MHz

Data Sheet

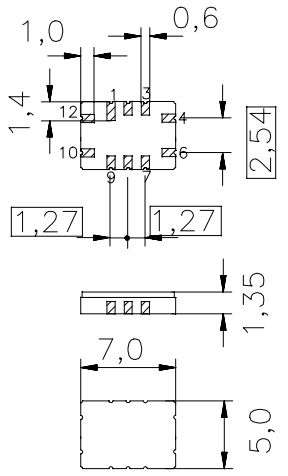
Ceramic package **QCC12B**

Features

- Low-loss IF filter for mobile telephone
- Channel selection in GSM, PCN, PCS systems
- Hermetically sealed ceramic SMD package
- Balanced and unbalanced operation possible
- Flat group delay response
- High stopband attenuation

Terminals

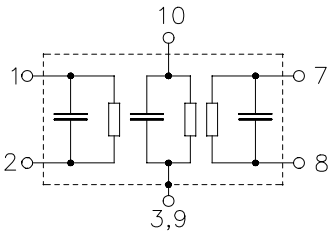
- Gold-plated Ni



Dimensions in mm, approx. weight 0,2 g

Pin configuration

2	Input
1	Input ground or balanced input
8	Output
7	Output ground or balanced output
10	Expansion Coil
3, 9	Case – ground
4, 6, 12	To be grounded



Type	Ordering code	Marking and Package according to	Packing according to
B4836	B39271-B4836-Z910	C61157-A7-A52	F61074-V8038-Z000

Electrostatic **S**ensitive **D**evice (**ESD**)

Maximum ratings

Operable temperature range	T	– 20/+ 70	˚C	
Storage temperature range	T_{stg}	– 25/+ 85	˚C	
DC voltage	V_{DC}	0	V	
Source power	P_s	10	dBm	

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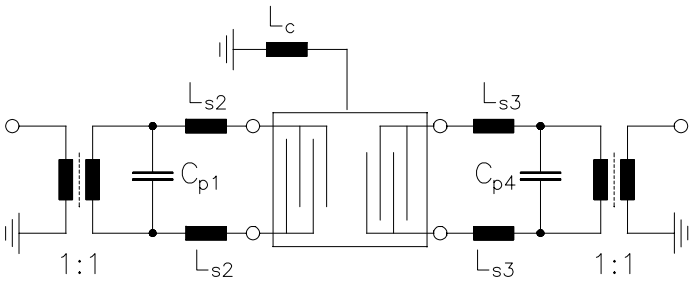
Characteristics

Operating temperature range: T = -20 to 70˚C
Terminating source impedance: Z_S = 520 Ω || -2,0 pF
Terminating load impedance: Z_L = 520 Ω || -2,0 pF

		min.	typ.	max.	
Nominal frequency	f_N	—	270,00	—	MHz
Minimum insertion attenuation	α_{min}				
including losses in matching circuit		3,5	4,5	5,5	dB
Amplitude ripple (p-p)	$\Delta\alpha$				
f_N - 87,5 kHz ... f_N + 87,5 kHz		—	0,3	2,0	dB
Group delay ripple (p-p)	$\Delta\tau$				
f_N - 87,5 kHz ... f_N + 87,5 kHz		—	0,7	1,3	µs
Insertion attenuation	α				
f_N - 25,0 MHz ... f_N - 3,00 MHz		55	65	—	dB
f_N - 3,00 MHz ... f_N - 1,60 MHz		46	64	—	dB
f_N - 1,60 MHz ... f_N - 0,60 MHz		38	53	—	dB
f_N - 0,60 MHz ... f_N - 0,40 MHz		30	54	—	dB
f_N - 0,40 MHz ... f_N - 0,20 MHz		5	10	—	dB
f_N + 0,20 MHz ... f_N + 0,40 MHz		5	10	—	dB
f_N + 0,40 MHz ... f_N + 0,60 MHz		28	32	—	dB
f_N + 0,60 MHz ... f_N + 1,60 MHz		38	43	—	dB
f_N + 1,60 MHz ... f_N + 3,00 MHz		46	49	—	dB
f_N + 3,00 MHz ... f_N + 25,0 MHz		55	63	—	dB
Impedance within the passband					
Input: $Z_{IN} = R_{IN} \parallel C_{IN}$		—	520 ‖ 2,0	—	Ω || pF
Output: $Z_{OUT} = R_{OUT} \parallel C_{OUT}$		—	520 ‖ 2,0	—	Ω || pF
Temperature coefficient of frequency [1]	TC_f	—	– 0,036	—	ppm/K^2
Turnover temperature	T_0	—	25	—	˚C

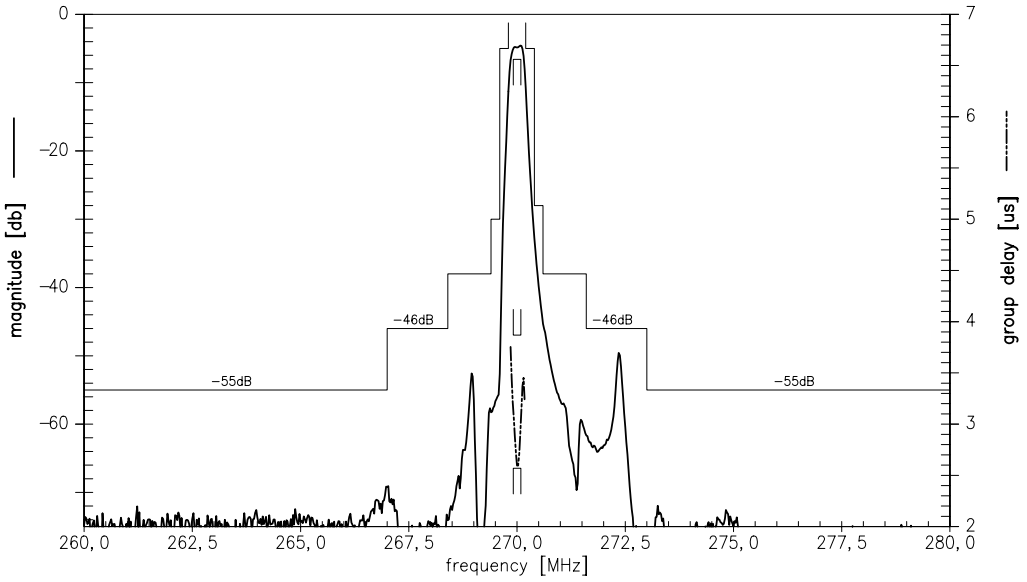
[1] Temperature dependence of f_c: $f_c(T) = f_c(T_0)(1 + TC_f(T - T_0)^2)$

Test matching network to 50 Ω (element values depend on PCB layout):



C_{p1} = 4,7 pF
L_{s2} = 56 nH
L_{s3} = 56 nH
C_{p4} = 4,7 pF
L_c = 82 nH

Transfer function:



Transfer function (pass band):